(05 Marks)

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ii) H - trees.

M. Tech. Degree Examination, Dec.2014/Jan.2015 Design of VLSI Systems

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∡ Tii	me: 3	3 hrs. Max. M	arks:100
		Note: Answer any FIVE full questions.	·00
9	5%		ar.
1	1	Praw and explain the 16 bit carry look ahead adder. Write down the expression	for critical
1	a.	Tab delay.	(08 Marks)
	b.	Explain array funnel shifter, with a neat diagram.	(06 Marks)
	c.	Explain the concept of hierarchy in VLSI designs.	(06 Marks)
	٧.		,
2	a.	With the help of a neat diagram, explain unsigned magnitude comparator.	(08 Marks)
2	а. b.	Explain the terms regularity, modularity and locality with one example for each	
	U.	the advantages of be approach?	(12 Marks)
		The maximum got of Topperone.	,,
3	•	Obtain the schematic of 8 multiplexer using 4: 1 multiplexer and 2: 1 multiple	ever
3	a.	Obtain the schematic of 674 multiplexer using 4.1 multiplexer and 2.1 multiplexer	(08 Marks)
	b.	Discuss the various components which accounts for nonrecurring engineering cos	•
			(07 Marks)
	c.	With necessary diagram, explain the simple Manchester adder with carry bypass.	(05 Marks)
4	a.	With the help of a 6T RAM explain memory read and write operation	and draw
		corresponding graphs.	(12 Marks)
	Ъ.	Draw and explain 4 × 4 CAM array. Give an application of CAM array and	explain the
		same.	(08 Mar ks)
5	a.	Design a BILBQ structure for linear feedback shift register implementing the	he function
		$f = 1 + x + x^3$. Deaw the schematic and explain.	(12 Marks)
	b.	Explain controllability, observability and fault coverage.	(08 Marks)
6	a.	Designand implement 3 – bit synchronous arbitrary counter to generate the seque	ence 0, 1, 2,
		3,65,7 and repeat using toggle flip flops.	(10 Marks)
	b.	Nat are error – correcting codes and gray codes? Explain with examples. 💢	(10 Marks)
	C	,	()
7	- ∖a.	What are serial and parallel divisions? Divide 13 by 34 using serial division i	
	, , ,	divide 11 by 2 using parallel method.	(12 Marks)
	b.	Explain bitrine conditioning in SRAM with the help of a diagram.	(04 Marks)
	c.	With the help of a diagram, explain column circuitry in a DRAM cell.	(04 Marks)
8	a.	With the help of a neat diagram, explain boundary scan architectures.	(10 Marks)
	b.	List the ideal properties of packaging.	(05 Marks)
	c.	Explain the following global clock distribution:	
		i) Grids	
		i) U troop	(AP36)

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